74HC1G66-Q100; 74HCT1G66-Q100 Single-pole single-throw analog switch Rev. 1 — 16 September 2013

Product data sheet

1. **General description**

The 74HC1G66-Q100; 74HCT1G66-Q100 is a single-pole, single-throw analog switch with two input/output terminals (nY and nZ) and a digital enable input (nE). When nE is LOW, the analog switch is turned off. Inputs include clamp diodes that enable the use of current limiting resistors to interface inputs to voltages in excess of V_{CC}.

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

Features and benefits 2.

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
 - ◆ Specified from -40 °C to +85 °C and from -40 °C to +125 °C
- Wide supply voltage range from 2.0 V to 10.0 V for the 74HC1G66-Q100
- Very low ON resistance:
 - \bullet 45 Ω (typ.) at $V_{CC} = 4.5 \text{ V}$
 - ◆ 30 Ω (typ.) at V_{CC} = 6.0 V
 - \bullet 25 Ω (typ.) at $V_{CC} = 9.0 \text{ V}$
- High noise immunity
- Low power dissipation
- Multiple package options
- ESD protection:
 - MIL-STD-883, method 3015 exceeds 2000 V
 - HBM JESD22-A114F exceeds 2000 V
 - MM JESD22-A115-A exceeds 200 V (C = 200 pf, R = 0 Ω)

Ordering information 3.

Table 1. **Ordering information**

Type number	Package	Package								
	Temperature range	Name	Description	Version						
74HC1G66GW-Q100	–40 °C to +125 °C	TSSOP5	plastic thin shrink small outline package;	SOT353-1						
74HCT1G66GW-Q100			5 leads; body width 1.25 mm							
74HC1G66GV-Q100	–40 °C to +125 °C	SC-74A	plastic surface-mounted package; 5 leads	SOT753						
74HCT1G66GV-Q100										

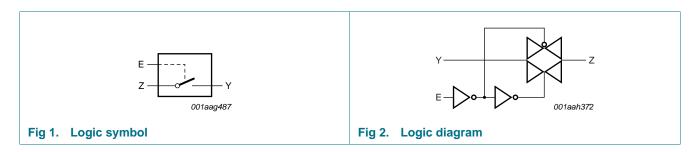


4. Marking

Table 2. Marking codes

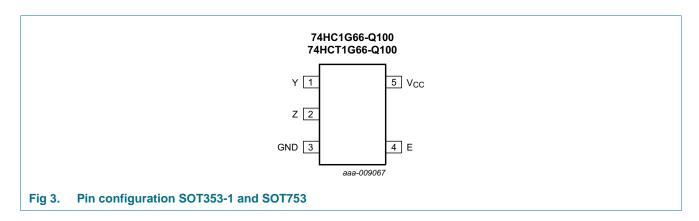
Type number	Marking	
74HC1G66GW-Q100	HL	
74HCT1G66GW-Q100	TL	
74HC1G66GV-Q100	H66	
74HCT1G66GV-Q100	T66	

5. Functional diagram



6. Pinning information

6.1 Pinning



6.2 Pin description

Table 3. Pin description

Symbol	Pin	Description
Υ	1	independent input or output
Z	2	independent input or output
GND	3	ground (0 V)
E	4	enable input (active HIGH)
V _{CC}	5	supply voltage

7. Functional description

Table 4. Function table[1]

Input E	Switch
L	OFF
Н	ON

^[1] H = HIGH voltage level; L = LOW voltage level.

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	supply voltage		-0.5	+11.0	V
I _{IK}	input clamping current	$V_I < -0.5 \text{ V or } V_I > V_{CC} + 0.5 \text{ V}$	<u>[1]</u> -	±20	mA
I _{SK}	switch clamping current	$V_I < -0.5 \text{ V or } V_I > V_{CC} + 0.5 \text{ V}$	<u>[1]</u> -	±20	mA
I _{SW}	switch current	V_{SW} > -0.5 V or V_{SW} < V_{CC} + 0.5 V	-	±25	mA
I _{CC}	supply current		-	50	mA
I _{GND}	ground current		-50	-	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	$T_{amb} = -40 ^{\circ}\text{C} \text{ to } +125 ^{\circ}\text{C}$	[2] _	250	mW

^[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

9. Recommended operating conditions

Table 6. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V).[1]

Symbol	bol Parameter Conditions		74H	74HC1G66-Q100			74HCT1G66-Q100		
			Min	Тур	Max	Min	Тур	Max	
V_{CC}	supply voltage		2.0	5.0	10.0	4.5	5.0	5.5	٧
V_{I}	input voltage		0	-	V_{CC}	0	-	V_{CC}	V
V_{SW}	switch voltage		0	-	V_{CC}	0	-	V_{CC}	V
T _{amb}	ambient temperature		-40	+25	+125	-40	+25	+125	°C
$\Delta t/\Delta V$	input transition rise	$V_{CC} = 2.0 \text{ V}$	-	-	625	-	-	-	ns/V
	and fall rate	V _{CC} = 4.5 V	-	1.67	139	-	1.67	139	ns/V
		$V_{CC} = 6.0 \text{ V}$	-	-	83	-	-	-	ns/V
		V _{CC} = 10.0 V	-	-	35	-	-	-	ns/V

^[1] To avoid drawing V_{CC} current from pin Z, when switch current flows in pin Y, the voltage drop across the bidirectional switch must not exceed 0.4 V. If the switch current flows into pin Z, no V_{CC} current flows from terminal Y. In this case, the voltage drop across the switch is unlimited, but the voltage at pins Y and Z may not exceed V_{CC} or GND.

^[2] For TSSOP5 and SC-74A packages: above 87.5 °C the value of Ptot derates linearly with 4.0 mW/K.

10. Static characteristics

Table 7. Static characteristics

Voltages are referenced to GND (ground = 0 V).

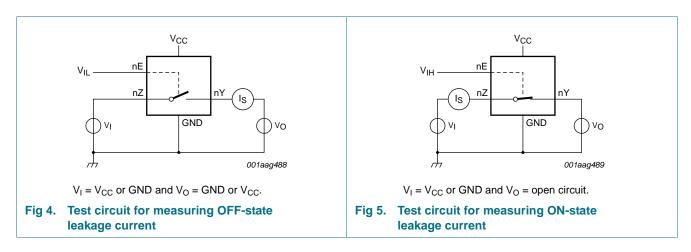
Symbol	Parameter	Conditions	-40	°C to +8	5 °C	-40 °C to	+125 °C	Unit
			Min	Typ[1]	Max	Min	Max	
74HC1G	66-Q100		'					'
V_{IH}	HIGH-level input	$V_{CC} = 2.0 \text{ V}$	1.5	1.2	-	1.5	-	V
	voltage	V _{CC} = 4.5 V	3.15	2.4	-	3.15	-	V
		V _{CC} = 6.0 V	4.2	3.2	-	4.2	-	V
		V _{CC} = 9.0 V	6.3	4.7	-	6.3	-	V
V _{IL}	LOW-level input	$V_{CC} = 2.0 \text{ V}$	-	0.8	0.5	-	0.5	V
	voltage	V _{CC} = 4.5 V	-	2.1	1.35	-	1.35	V
		V _{CC} = 6.0 V	-	2.8	1.8	-	1.8	V
		V _{CC} = 9.0 V	-	4.3	2.7	-	2.7	V
II	input leakage current	E; $V_I = V_{CC}$ or GND						
		V _{CC} = 6.0 V	-	0.1	1.0	-	1.0	μΑ
		V _{CC} = 10.0 V	-	0.2	2.0	-	2.0	μΑ
I _{S(OFF)}	OFF-state leakage current	Y or Z; V _{CC} = 10 V; see <u>Figure 4</u>	-	0.1	1.0	-	1.0	μΑ
I _{S(ON)}	ON-state leakage current	Y or Z; $V_{CC} = 10 \text{ V}$; see Figure 5	-	0.1	1.0	-	1.0	μΑ
I _{CC}	supply current	E, Y or Z; $V_1 = V_{CC}$ or GND; $V_{SW} = GND$ or V_{CC}						
		V _{CC} = 6.0 V	-	1.0	10	-	20	μΑ
		V _{CC} = 10.0 V	-	2.0	20	-	40	μΑ
Cı	input capacitance		-	1.5	-	-	-	pF
$C_{S(ON)}$	ON-state capacitance		-	8	-	-	-	pF

Table 7. Static characteristics ...continued Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	-40	°C to +8	5 °C	–40 °C to	+125 °C	Unit
			Min	Typ[1]	Max	Min	Max	
74HCT1	G66-Q100		•	'			•	
V_{IH}	HIGH-level input voltage	$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	2.0	1.6	-	2.0	-	V
V_{IL}	LOW-level input voltage	$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	0.1	1.2	8.0	-	0.8	V
I _I	input leakage current	E; $V_I = V_{CC}$ or GND; $V_{CC} = 5.5 \text{ V}$	-	0.1	1.0	-	1.0	μΑ
I _{S(OFF)}	OFF-state leakage current	Y or Z; $V_{CC} = 5.5 \text{ V}$; see Figure 4	-	0.1	1.0	-	1.0	μΑ
I _{S(ON)}	ON-state leakage current	Y or Z; $V_{CC} = 5.5 \text{ V}$; see Figure 5	-	0.1	1.0	-	1.0	μΑ
I _{CC}	supply current	E, Y or Z; $V_1 = V_{CC}$ or GND; $V_{SW} = GND$ or V_{CC} ; $V_{CC} = 4.5$ V to 5.5 V	-	1	10	-	20	μΑ
ΔI_{CC}	additional supply current	$V_I = V_{CC} - 2.1$ V; $V_{CC} = 4.5$ V to 5.5 V; $I_O = 0$ A	-	-	500	-	850	μΑ
Cı	input capacitance		-	1.5	-	-	-	pF
$C_{S(ON)}$	ON-state capacitance		-	8	-	-	-	pF

^[1] Typical values are measured at $T_{amb} = 25$ °C.

10.1 Test circuits



10.2 ON resistance

Table 8. ON resistance

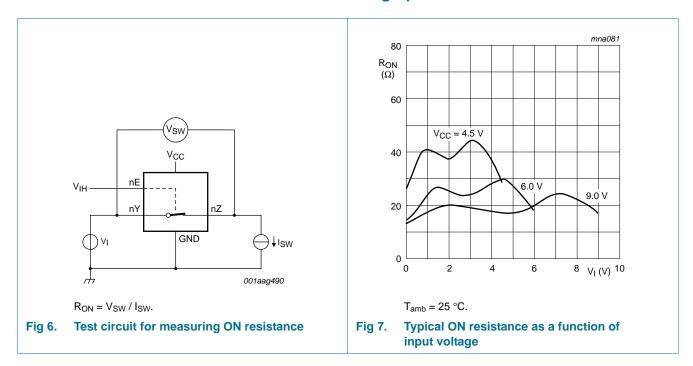
At recommended operating conditions; voltages are referenced to GND (ground 0 V); for graph see Figure 7.

Symbol	Parameter	Conditions	-40	°C to +8	5 °C	–40 °C	Unit	
			Min	Typ[2]	Max	Min	Max	
74HC1G6	6-Q100 <u>[1]</u>			1	1			'
R _{ON(peak)}		$V_I = GND$ to V_{CC} ; see Figure 6						
	(peak)	$I_{SW} = 0.1 \text{ mA}; V_{CC} = 2.0 \text{ V}$	-	-	-	-	-	Ω
		$I_{SW} = 1 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	42	118	-	142	Ω
		$I_{SW} = 1 \text{ mA}; V_{CC} = 6.0 \text{ V}$	-	31	105	-	126	Ω
		$I_{SW} = 1 \text{ mA}; V_{CC} = 9.0 \text{ V}$	-	23	88	-	105	Ω
R _{ON(rail)}	ON resistance (rail)	V _I = GND; see <u>Figure 6</u>						
		$I_{SW} = 0.1 \text{ mA}; V_{CC} = 2.0 \text{ V}$	-	75	-	-	-	Ω
		$I_{SW} = 1 \text{ mA}$; $V_{CC} = 4.5 \text{ V}$	-	29	95	-	115	Ω
		$I_{SW} = 1 \text{ mA}$; $V_{CC} = 6.0 \text{ V}$	-	23	82	-	100	Ω
		$I_{SW} = 1 \text{ mA}; V_{CC} = 9.0 \text{ V}$	-	18	70	-	80	Ω
		V _I = V _{CC} ; see <u>Figure 6</u>						
		$I_{SW} = 0.1 \text{ mA}; V_{CC} = 2.0 \text{ V}$	-	75	-	-	-	Ω
		$I_{SW} = 1 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	35	106	-	128	Ω
		$I_{SW} = 1 \text{ mA}$; $V_{CC} = 6.0 \text{ V}$	-	27	94	-	113	Ω
		$I_{SW} = 1 \text{ mA}; V_{CC} = 9.0 \text{ V}$	-	21	78	-	95	Ω
74HCT16	666-Q100							
R _{ON(peak)}	ON resistance	$V_I = GND \text{ to } V_{CC}; \text{ see } \frac{\text{Figure 6}}{}$						
	(peak)	$I_{SW} = 1 \text{ mA}$; $V_{CC} = 4.5 \text{ V}$	-	42	118	-	142	Ω
$R_{ON(rail)} \\$	ON resistance (rail)	$V_I = GND$; see Figure 6						
		$I_{SW} = 1 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	29	95	-	115	Ω
		$V_1 = V_{CC}$; see <u>Figure 6</u>						
		$I_{SW} = 1 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	35	106	-	128	Ω

^[1] At supply voltages approaching 2 V, the ON resistance becomes extremely non-linear. Therefore it is recommended that these devices be used to transmit digital signals only, when using this supply voltage.

^[2] Typical values are measured at T_{amb} = 25 °C.

10.3 ON resistance test circuit and graphs



11. Dynamic characteristics

Table 9. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); $C_L = 50 \text{ pF}$; $R_L = 1 \text{ k}\Omega$, unless otherwise specified; For test circuit, see <u>Figure 10</u>.

Symbol	Parameter	Conditions		-40 °C to +85 °C			-40 °C t	Unit	
			Min	Typ[1]	Max	Min	Max		
74HC1G	66-Q100		'		'		'	•	•
t _{pd}	propagation delay	Y to Z or Z to Y; $R_L = \infty \Omega$; see Figure 8	[2]						
		V _{CC} = 2.0 V		-	8	75	-	90	ns
		V _{CC} = 4.5 V		-	3	15	-	18	ns
		$V_{CC} = 6.0 \text{ V}$		-	2	13	-	15	ns
		V _{CC} = 9.0 V		-	1	10	-	12	ns
t _{en}	enable time	E to Y or Z; see Figure 9	[2]						
		$V_{CC} = 2.0 \text{ V}$		-	50	125	-	150	ns
		V _{CC} = 4.5 V		-	16	25	-	30	ns
		$V_{CC} = 5.0 \text{ V}; C_L = 15 \text{ pF}$		-	11	-	-	-	ns
		$V_{CC} = 6.0 \text{ V}$		-	13	21	-	26	ns
		V _{CC} = 9.0 V		-	9	16	-	20	ns

 Table 9.
 Dynamic characteristics ...continued

Voltages are referenced to GND (ground = 0 V); $C_L = 50$ pF; $R_L = 1$ k Ω , unless otherwise specified; For test circuit, see Figure 10.

Symbol	Parameter	Conditions		-40	°C to +8	5 °C	-40 °C t	o +125 °C	Unit
				Min	Typ[1]	Max	Min	Max	
t _{dis}	disable time	E to Y or Z; see Figure 9	[2]		'	1	'	1	
		V _{CC} = 2.0 V		-	27	190	-	225	ns
		V _{CC} = 4.5 V		-	16	38	-	45	ns
		$V_{CC} = 5.0 \text{ V}; C_L = 15 \text{ pF}$		-	11	-	-	-	ns
		V _{CC} = 6.0 V		-	14	33	-	38	ns
		V _{CC} = 9.0 V		-	12	16	-	20	ns
C_{PD}	power dissipation capacitance	$V_I = GND \text{ to } V_{CC}$	<u>[3]</u>	-	9	-	-	-	pF
74HCT1	G66-Q100								
t _{pd}	propagation delay	Y to Z or Z to Y; $R_L = \infty \Omega$; see Figure 8	[2]						
		V _{CC} = 4.5 V		-	3	15	-	18	ns
t _{en}	enable time	E to Y or Z; see Figure 9	[2]						
		V _{CC} = 4.5 V		-	15	30	-	36	ns
		$V_{CC} = 5.0 \text{ V}; C_L = 15 \text{ pF}$		-	12	-	-	-	ns
t _{dis}	disable time	E to Y or Z; see Figure 9	[2]						
		V _{CC} = 4.5 V		-	13	44	-	53	ns
		$V_{CC} = 5.0 \text{ V}; C_L = 15 \text{ pF}$		-	12	-	-	-	ns
C_{PD}	power dissipation capacitance	$V_I = GND \text{ to } V_{CC} - 1.5 \text{ V}$	<u>[3]</u>	-	9	-	-	-	pF

^[1] All typical values are measured at T_{amb} = 25 °C.

 t_{en} is the same as t_{PZL} and $t_{\text{PZH}}.$

 t_{dis} is the same as t_{PLZ} and $t_{\text{PHZ}}.$

[3] C_{PD} is used to determine the dynamic power dissipation P_D (μW).

$$P_D = C_{PD} \times V_{CC}{}^2 \times f_i + \Sigma \; ((C_L \times C_{SW}) \times V_{CC}{}^2 \times f_o) \; \text{where:} \;$$

 f_i = input frequency in MHz;

f_o = output frequency in MHz;

C_L = output load capacitance in pF;

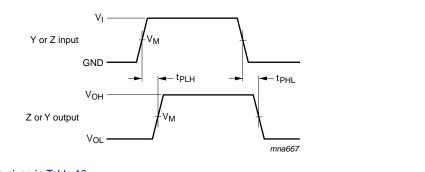
 C_{SW} = maximum switch capacitance in pF (see <u>Table 7</u>);

V_{CC} = supply voltage in Volt;

 $\Sigma ((C_L \times C_{SW}) \times V_{CC}^2 \times f_o) = \text{sum of outputs.}$

^[2] t_{pd} is the same as t_{PLH} and t_{PHL} .

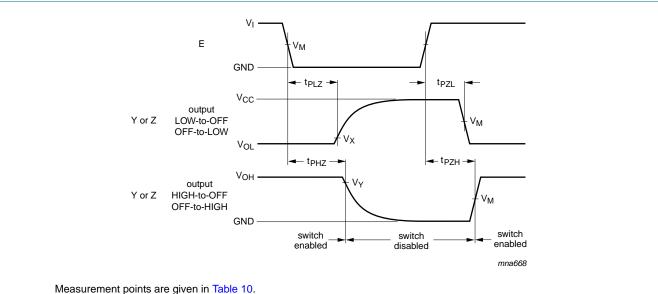
11.1 Waveforms and test circuit



Measurement points are given in Table 10.

Logic levels: V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Fig 8. Input (Y or Z) to output (Z or Y) propagation delays



ineasurement points are given in table 10

Enable and disable times

Logic levels: V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Table 10. Measurement points

Туре	Input	Output	Output				
	V _M	V _M	V _X	V _Y			
74HC1G66-Q100	0.5V _{CC}	0.5V _{CC}	V _{OL} + 10%	V _{OH} – 10%			
74HCT1G66-Q100	1.3 V	1.3 V	V _{OL} + 10%	V _{OH} – 10%			

Fig 9.

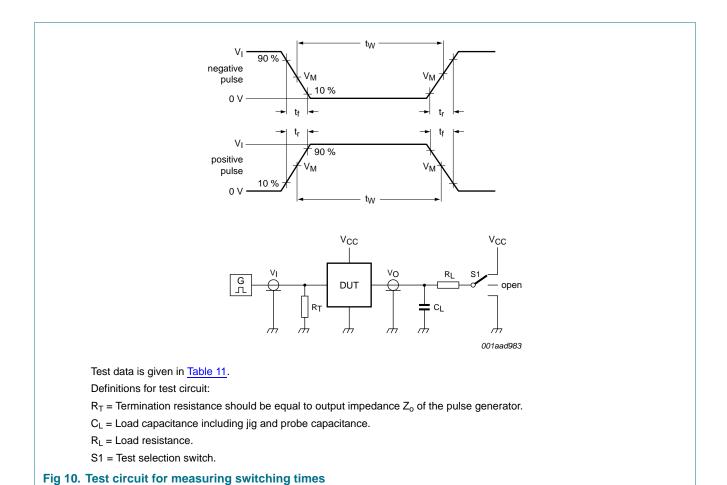


Table 11. Test data

Туре	Input		Load		S1 position			
	V _I	t _r , t _f [1]	CL	R _L	t _{PHL} , t _{PLH}	t _{PZH} , t _{PHZ}	t _{PZL} , t _{PLZ}	
74HC1G66-Q100	GND to V_{CC}	6 ns	50 pF, 15 pF	1 k Ω , ∞ Ω	open	GND	V _{CC}	
74HCT1G66-Q100	GND to 3 V	6 ns	50 pF, 15 pF	1 k Ω , ∞ Ω	open	GND	V _{CC}	

^[1] There is no constraint on t_r, t_f with a 50% duty factor when measuring f_{max}.

11.2 Additional dynamic characteristics

Table 12. Additional dynamic characteristics for 74HC1G66-Q100 and 74HCT1G66-Q100 $GND = 0 \ V; \ t_r = t_f = 6.0 \ ns; \ C_L = 50 \ pF; \ unless \ otherwise \ specified.$ All typical values are measured at $T_{amb} = 25 \ ^{\circ}C.$

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
THD	total harmonic	$f_i = 1 \text{ kHz}$; $R_L = 10 \text{ k}\Omega$; see Figure 11				%
	distortion	$V_{CC} = 4.5 \text{ V}; V_I = 4.0 \text{ V (p-p)}$	-	0.04	-	%
	f	$V_{CC} = 9.0 \text{ V}; V_I = 8.0 \text{ V (p-p)}$	-	0.02	-	%
		$f_i = 10 \text{ kHz}$; $R_L = 10 \text{ k}\Omega$; see Figure 11				
		$V_{CC} = 4.5 \text{ V}; V_I = 4.0 \text{ V (p-p)}$	-	0.12	-	%
		$V_{CC} = 9.0 \text{ V}; V_I = 8.0 \text{ V (p-p)}$	-	0.06	-	%

74HC_HCT1G66_Q100

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Table 12. Additional dynamic characteristics for 74HC1G66-Q100 and 74HCT1G66-Q100 ...continued $GND = 0 \ V; \ t_r = t_f = 6.0 \ ns; \ C_L = 50 \ pF; \ unless \ otherwise \ specified.$ All typical values are measured at $T_{amb} = 25 \ ^{\circ}C$.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$f_{(-3dB)}$	-3 dB frequency	$R_L = 50 \Omega$; $C_L = 10 pF$; see Figure 12 and 13				
	response	V _{CC} = 4.5 V	-	180	-	MHz
		V _{CC} = 9.0 V	-	200	-	MHz
α_{iso}	isolation (OFF-state)	$R_L = 600 \Omega$; $f_i = 1 MHz$; see Figure 14 and 15				
		V _{CC} = 4.5 V	-	-50	-	dB
		V _{CC} = 9.0 V	-	-50	-	dB

11.3 Test circuits and graphs

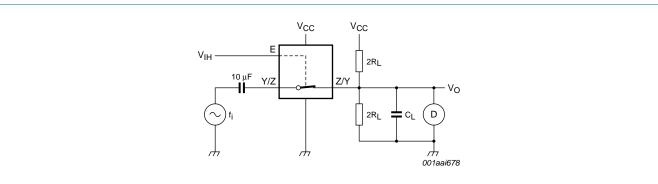
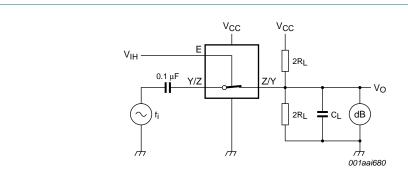


Fig 11. Test circuit for measuring total harmonic distortion



With f_i = 1 MHz, adjust the switch input voltage for a 0 dBm level at the switch output (0 dBm = 1 mW into 50 Ω). Then Increase the input frequency until the dB meter reads -3 dB

Fig 12. Test circuit for measuring the -3 dB frequency response

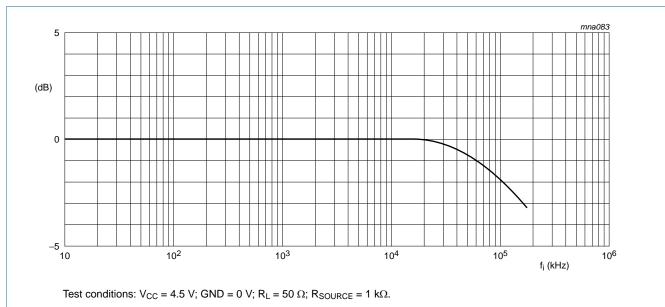
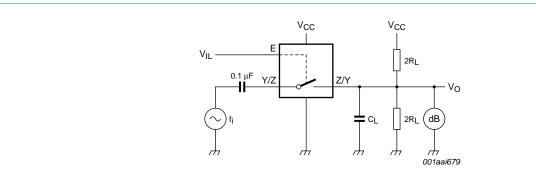
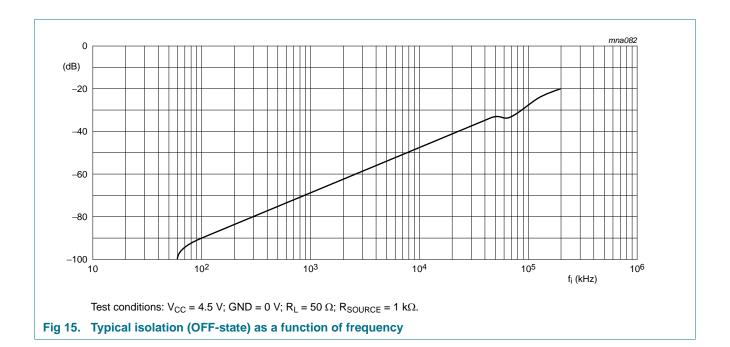


Fig 13. Typical –3 dB frequency response



Adjust the switch input voltage for a 0 dBm level (0 dBm = 1 mW into 600 Ω)

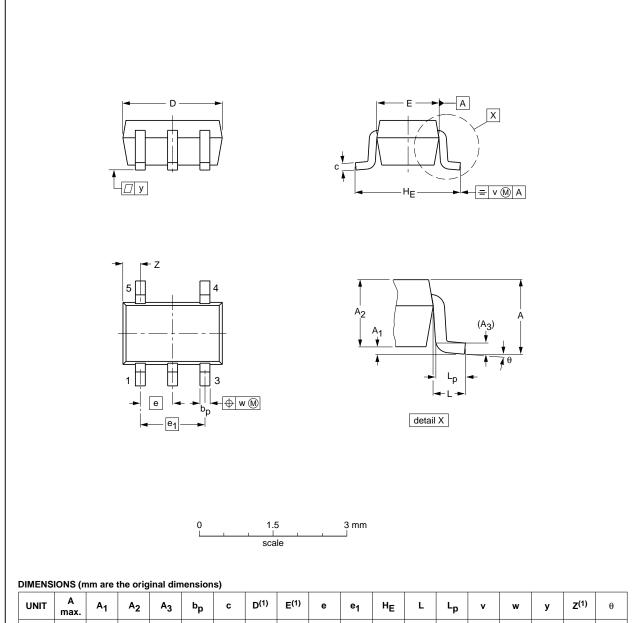
Fig 14. Test circuit for measuring isolation (OFF-state)



12. Package outline

TSSOP5: plastic thin shrink small outline package; 5 leads; body width 1.25 mm

SOT353-1



UNIT	A max.	A ₁	A ₂	Α3	bp	С	D ⁽¹⁾	E ⁽¹⁾	e	e ₁	HE	L	Lp	v	w	у	Z ⁽¹⁾	θ
mm	1.1	0.1 0	1.0 0.8	0.15	0.30 0.15	0.25 0.08	2.25 1.85	1.35 1.15	0.65	1.3	2.25 2.0	0.425	0.46 0.21	0.3	0.1	0.1	0.60 0.15	7° 0°

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.

OUTLINE		REFER	RENCES	EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	JEITA	PROJECTION	1330E DATE	
SOT353-1		MO-203	SC-88A		-00-09-01 03-02-19	

Fig 16. Package outline SOT353-1 (TSSOP5)

Plastic surface-mounted package; 5 leads

SOT753

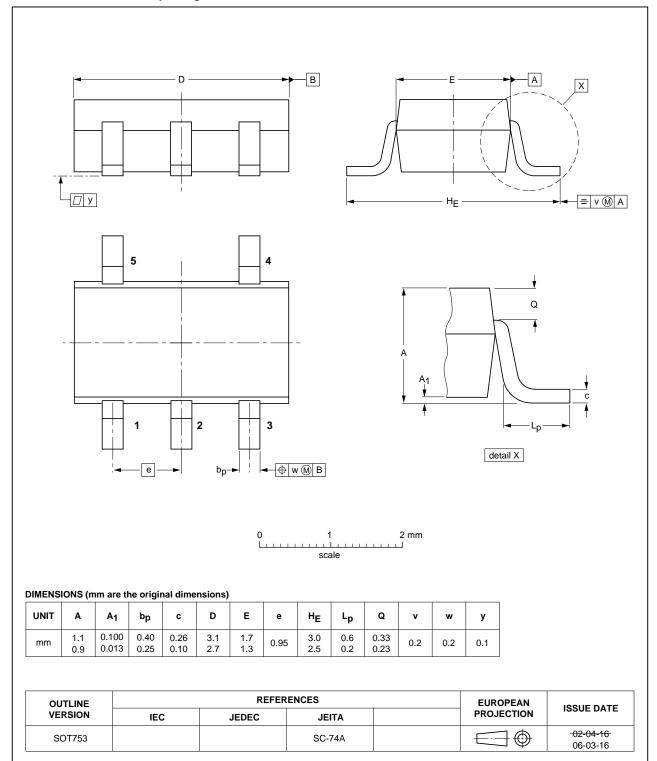


Fig 17. Package outline SOT753 (SC-74A)

13. Abbreviations

Table 13. Abbreviations

Acronym	Description
CMOS	Complementary Metal-Oxide Semiconductor
ESD	ElectroStatic Discharge
НВМ	Human Body Model
MM	Machine Model
TTL	Transistor-Transistor Logic
DUT	Device Under Test

14. Revision history

Table 14. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74HC_HCT1G66_Q100 v.1	20130916	Product data sheet	-	-

15. Legal information

15.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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74HC1G66-Q100; 74HCT1G66-Q100

Single-pole single-throw analog switch

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NXP Semiconductors

Single-pole single-throw analog switch

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